



N-Channel Field Effect Transistor

PRODUCT SUMMARY

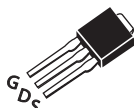
V _{DSS}	I _D	R _{DS(ON)} (Ω) Typ
250V	2A	3.2 @ V _{GS} =10V

FEATURES

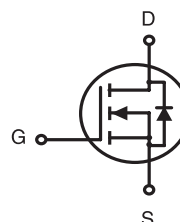
- Super high dense cell design for low R_{DS(ON)}.
- Rugged and reliable.
- Surface Mount Package.



SDU SERIES
TO - 252AA(D-PAK)



SDD SERIES
TO - 251(I-PAK)



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Symbol	Parameter		Limit	Units
V _{DS}	Drain-Source Voltage		250	V
V _{GS}	Gate-Source Voltage		±30	V
I _D	Drain Current-Continuous	T _A =25°C	2	A
		T _A =70°C	1.5	A
I _{DM}	-Pulsed ^a		6	A
E _{AS}	Single Pulse Avalanche Energy ^c		10.4	mJ
P _D	Maximum Power Dissipation	T _A =25°C	42	W
		T _A =70°C	27	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range		-55 to 150	°C

THERMAL CHARACTERISTICS

R _{θJC}	Thermal Resistance, Junction-to-Case	3	°C/W
R _{θJA}	Thermal Resistance, Junction-to-Ambient	50	°C/W

SDU/D02N25

Ver 1.1

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	250			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =200V , V _{GS} =0V			1	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±30V , V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	2	3	4	V
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =10V , I _D =1A		3.2	4.2	ohm
g _{FS}	Forward Transconductance	V _{DS} =10V , I _D =1A		0.9		S
DYNAMIC CHARACTERISTICS ^b						
C _{ISS}	Input Capacitance	V _{DS} =25V,V _{GS} =0V f=1.0MHz		185		pF
C _{OSS}	Output Capacitance			31		pF
C _{RSS}	Reverse Transfer Capacitance			6.1		pF
SWITCHING CHARACTERISTICS ^b						
t _{D(ON)}	Turn-On Delay Time	V _{DD} =125V I _D =1A V _{GS} =10V R _{GEN} =25 ohm		13.4		ns
t _r	Rise Time			12.2		ns
t _{D(OFF)}	Turn-Off Delay Time			21.5		ns
t _f	Fall Time			5.6		ns
Q _g	Total Gate Charge	V _{DS} =125V,I _D =1A,V _{GS} =10V		4.36		nC
Q _{gs}	Gate-Source Charge	V _{DS} =125V,I _D =1A, V _{GS} =10V		1.28		nC
Q _{gd}	Gate-Drain Charge			1.48		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	V _{GS} =0V,I _S =1A		0.81	1.4	V

Notes

- a. Pulse Test: Pulse Width < 300us, Duty Cycle < 2%.
b. Guaranteed by design, not subject to production testing.
c. Starting T_J=25°C, L=1mH, R_G=25Ω, V_{DD} = 50V. (See Figure12)

Jun,07,2012

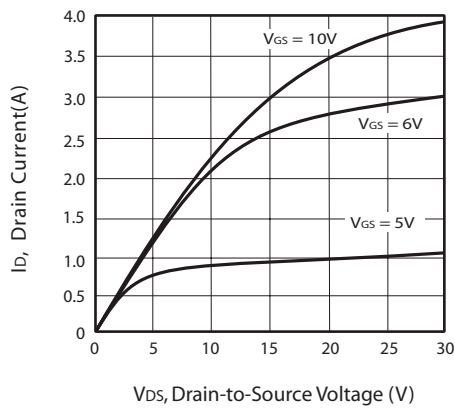


Figure 1. Output Characteristics

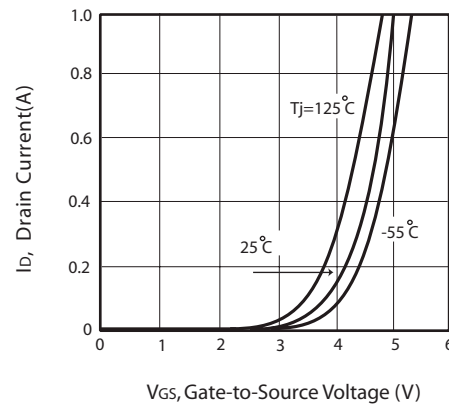


Figure 2. Transfer Characteristics

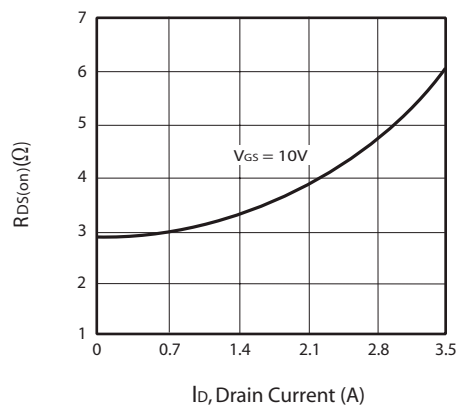


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

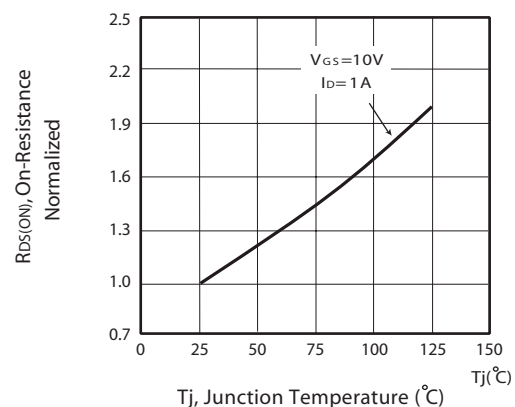


Figure 4. On-Resistance Variation with Drain Current and Temperature

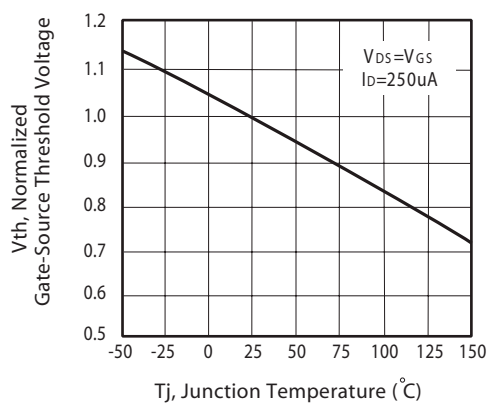


Figure 5. Gate Threshold Variation with Temperature

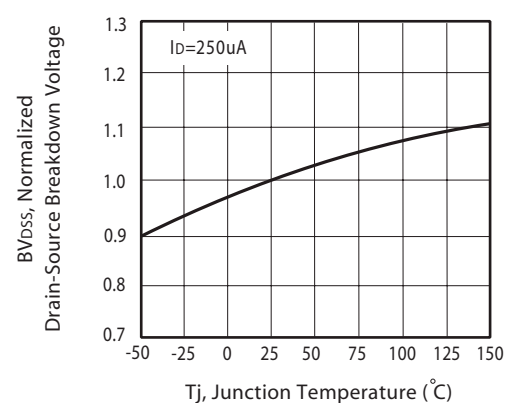


Figure 6. Breakdown Voltage Variation with Temperature

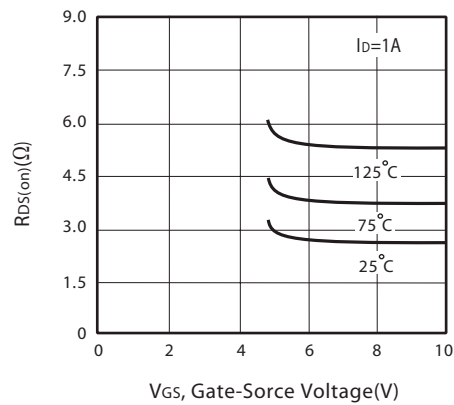


Figure 7. On-Resistance vs. Gate-Source Voltage

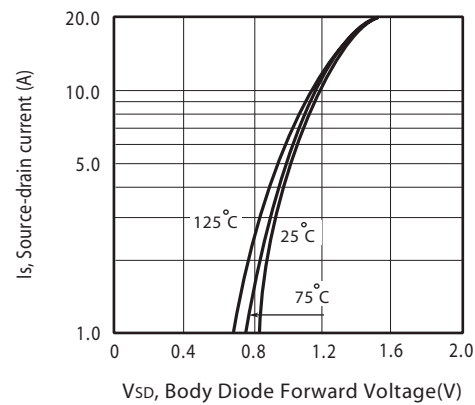


Figure 8. Body Diode Forward Voltage Variation with Source Current

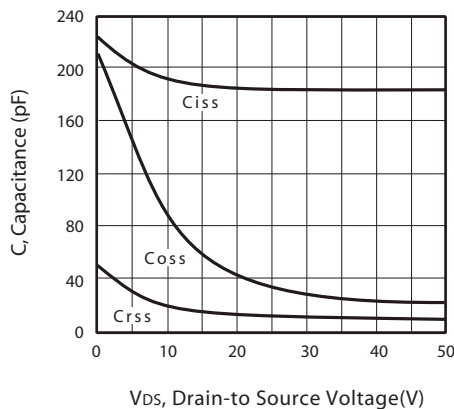


Figure 9. Capacitance

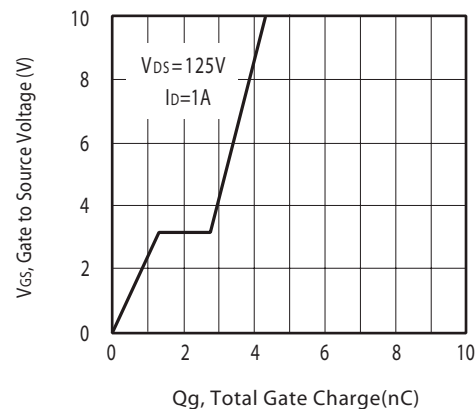


Figure 10. Gate Charge

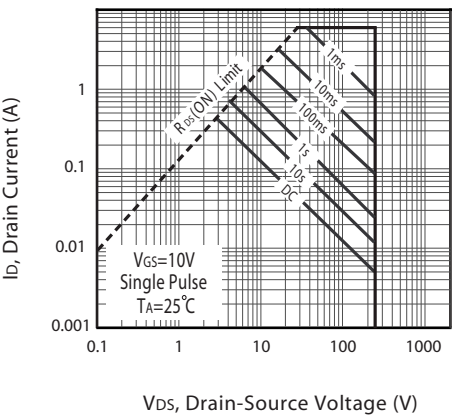
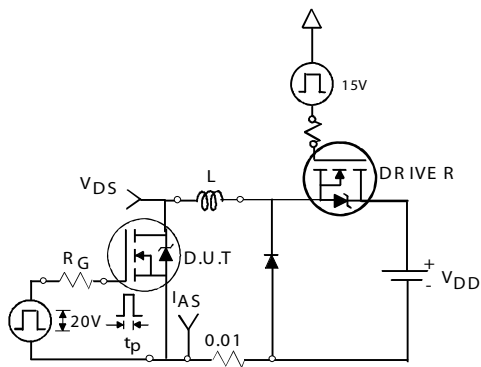
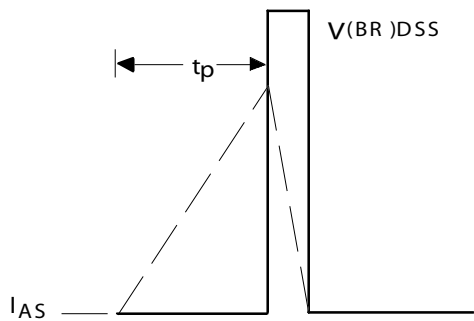


Figure 11. Maximum Safe Operating Area



Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

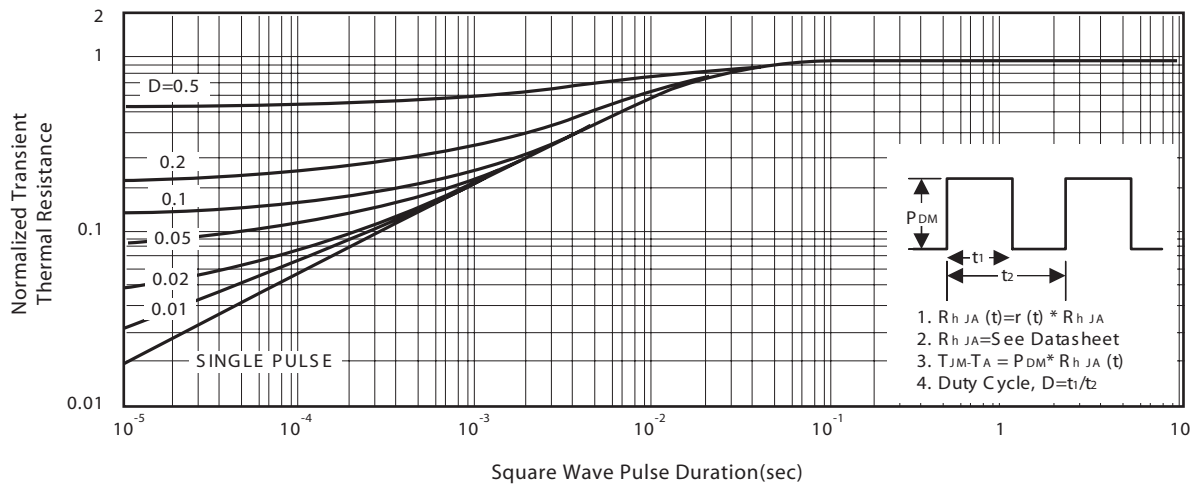
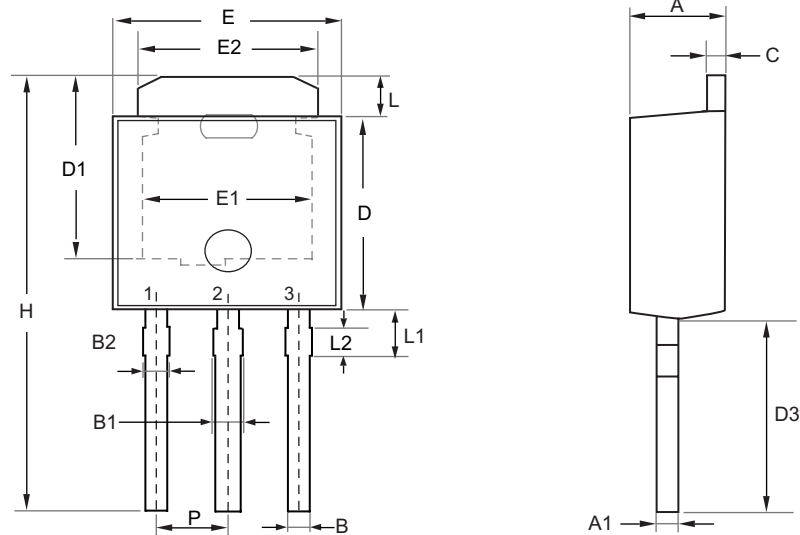


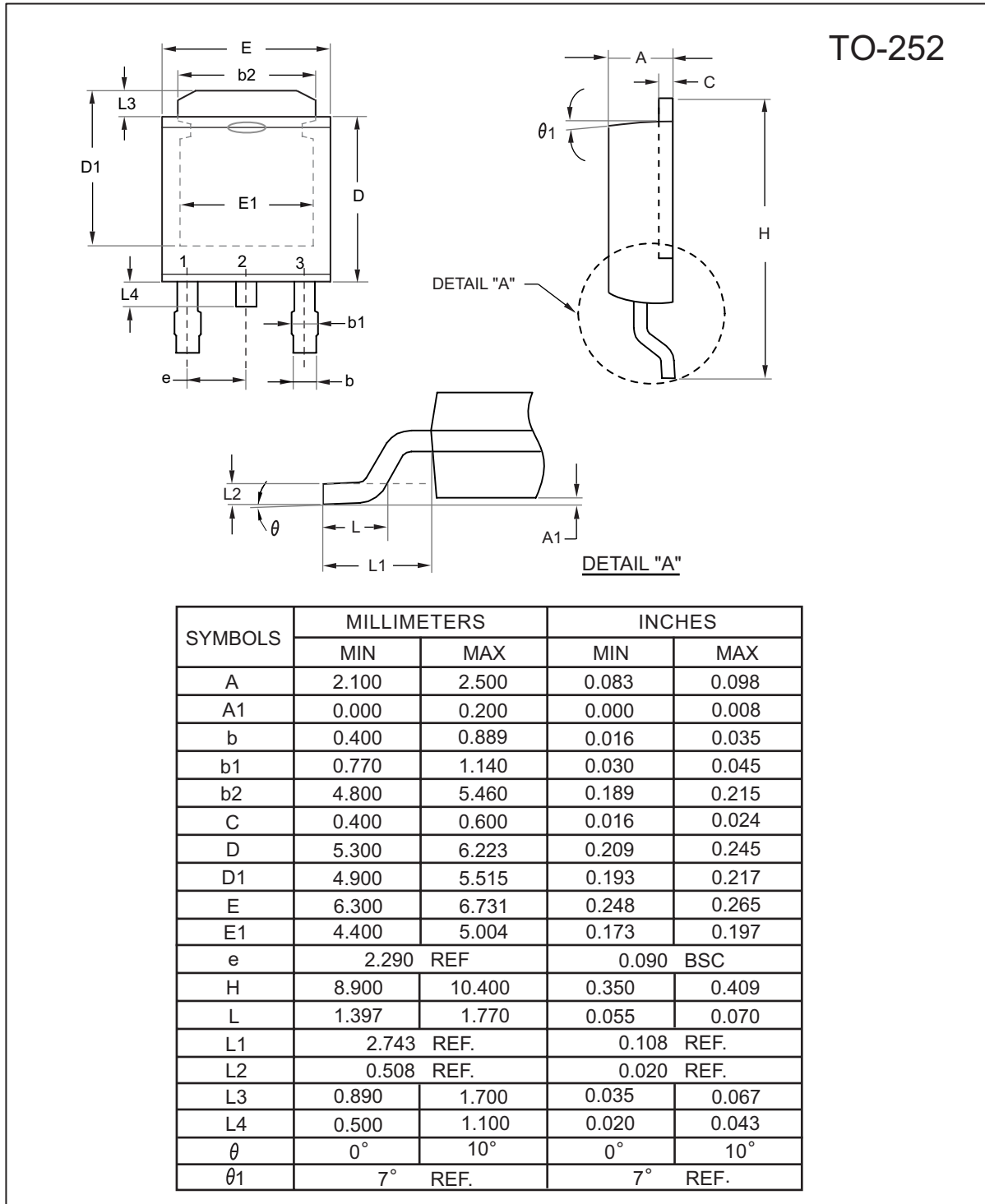
Figure 14. Normalized Thermal Transient Impedance Curve

PACKAGE OUTLINE DIMENSIONS

TO-251

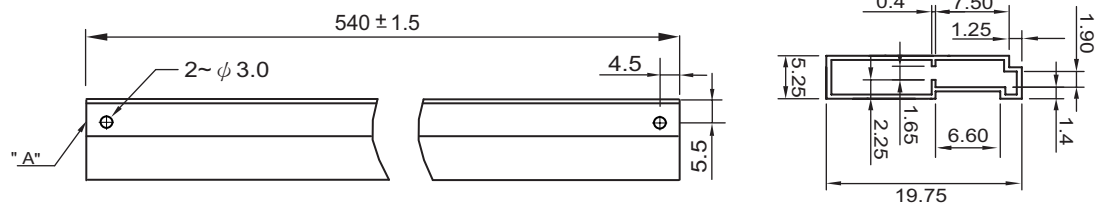


SYMBOL	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.100	2.500	0.083	0.098
A1	0.350	0.650	0.014	0.026
B	0.400	0.800	0.016	0.031
B1	0.650	1.140	0.026	0.045
B2	0.500	0.900	0.020	0.035
C	0.400	0.600	0.016	0.024
D	5.300	6.223	0.209	0.245
D1	4.900	5.300	0.193	0.209
D3	3.980	4.280	0.157	0.169
H	11.050	11.450	0.435	0.451
E	6.300	6.700	0.248	0.264
E1	4.400	4.900	0.181	0.193
E2	4.800	5.460	0.189	0.215
L	1.300	1.700	0.051	0.067
L1	0.972	1.226	0.038	0.048
L2	0.500	0.900	0.020	0.035
P	2.300 BSC		0.091 BSC	

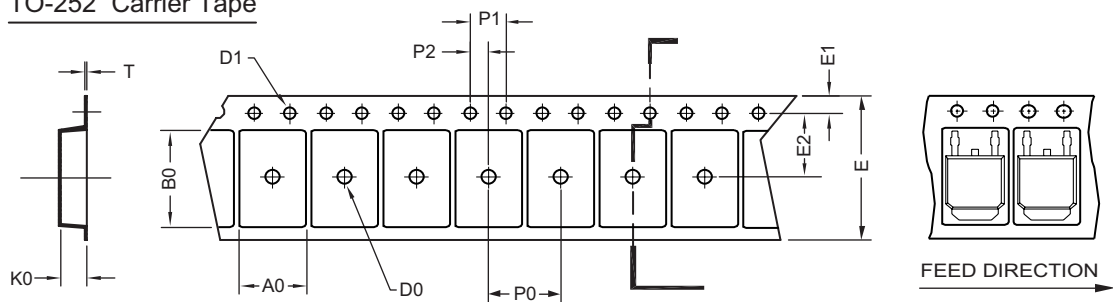


TO-251 Tube/TO-252 Tape and Reel Data

TO-251 Tube



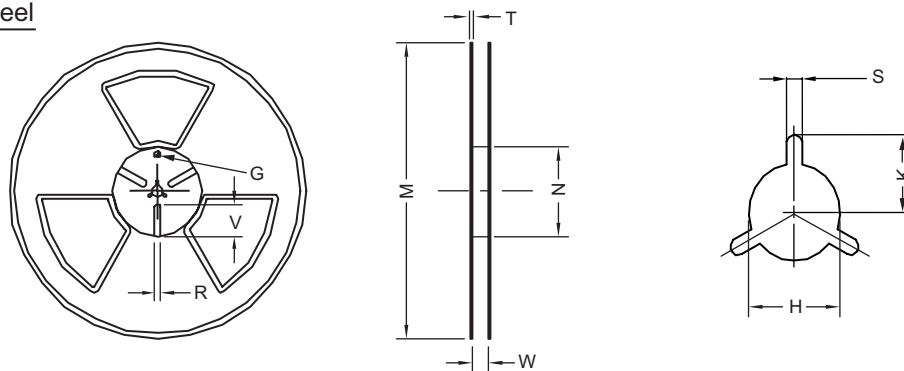
TO-252 Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
TO-252 (16 mm)	6.96 ±0.1	10.49 ±0.1	2.79 ±0.1	φ 2	φ 1.5 + 0.1 - 0	16.0 ±0.3	1.75 ±0.1	7.5 ±0.15	8.0 ±0.1	4.0 ±0.1	2.0 ±0.15	0.3 ±0.05

TO-252 Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	T	H	K	S	G	R	V
16 mm	φ 330	φ 330 ± 0.5	φ 97 ± 1.0	17.0 + 1.5 - 0	2.2	φ 13.0 + 0.5 - 0.2	10.6	2.0 ±0.5	---	---	---